TOSHIBA TCD2701C

TENTATIVE

TOSHIBA CCD LINEAR IMAGE SENSOR CCD (Charge Coupled Device)

TCD2701C

The TCD2701C is a high sensitive and low dark current 7500 elements x 3 line CCD color image sensor.

The sensor is designed for color scanner.

The device contains a row of 7500 elements x 3 line photodiodes which provide a 24 lines/mm across a A3 size paper. The device is operated by 5 V pulse, and 12 V power supply.

FEATURES

Number of Image Sensing Elements

: 7500 elements x 3 line

Image Sensing Element Size : 9.325 μ m by 9.325 μ m on

9.325 μ m centers

Photo Sensing Region : High sensitive pn photodiode

Clock : 2 phase (5 V)

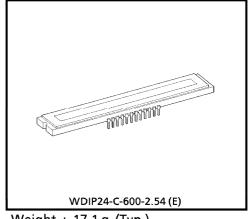
Distance Between Photodiode Array : 37.3 μ m (4 Lines)

Internal Circuit : Clamp circuit Package : 24 pin DIP Color Filter : Red, Green, Blue

MAXIMUM RATINGS (Note 1)

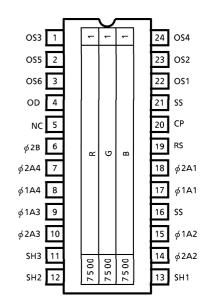
CHARACTERISTIC	SYMBOL	RATING	UNIT
Clock Pulse Voltage	Vφ		V
Shift Pulse Voltage	V _{SH}	-0.3~8	
Reset Pulse Voltage	V _{RS}	-0.5~6	
Clamp Pulse Voltage	VCP		
Power Supply Voltage	V _{OD}	-0.3~15	V
Operating Temperature	Topr	0~60	°C
Storage Temperature	T _{stg}	- 25∼85	°C

(Note 1): All voltage are with respect to SS terminals (Ground).



Weight: 17.1 g (Typ.)

PIN CONNECTIONS



(TOP VIEW)

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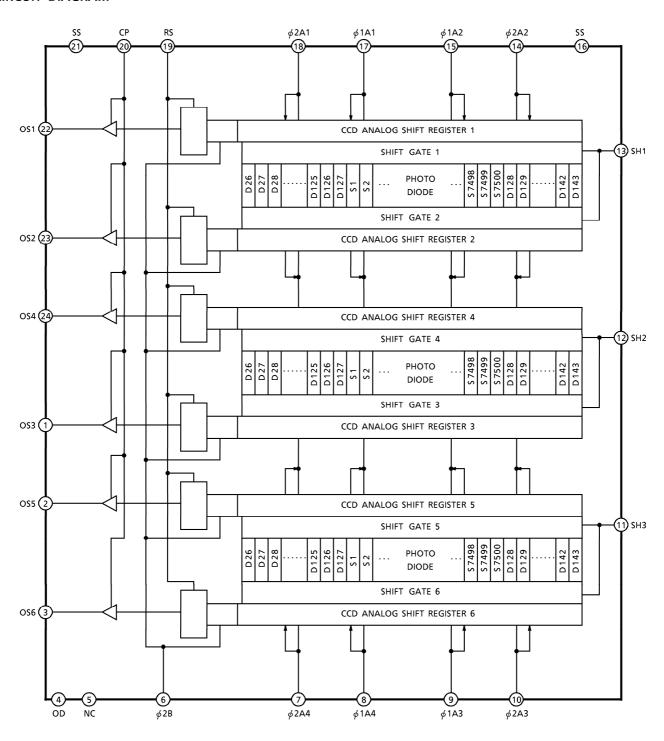
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CIRCUIT DIAGRAM



PIN NAMES

PIN No.	SYMBOL	NAME	PIN No.	SYMBOL	NAME
1	OS3	Signal Output 3 (Green)	13	SH1	Shift Gate 1
2	OS5	Signal Output 5 (Red)	14	φ2A2	Clock 2 (Phase 2)
3	OS6	Signal Output 6 (Red)	15	φ1A2	Clock 2 (Phase 1)
4	OD	Power	16	SS	Ground
5	NC	Non Connection	17	ø1A1	Clock 1 (Phase 1)
6	φ2B	Final Stage Clock (Phase 2)	18	φ2 A 1	Clock 1 (Phase 2)
7	φ2A4	Clock 4 (Phase 2)	19	RS	Reset Gate
8	φ1A4	Clock 4 (Phase 1)	20	СР	Clamp Gate
9	φ1A3	Clock 3 (Phase 1)	21	SS	Ground
10	φ2A3	Clock 3 (Phase 2)	22	OS1	Signal Output 1 (Blue)
11	SH3	Shift Gate 3	23	OS2	Signal Output 2 (Blue)
12	SH2	Shift Gate 2	24	OS4	Signal Output 4 (Green)

OPTICAL / ELECTRICAL CHARACTERISTICS

(Ta = 25°C, V $_{OD}$ = 12 V, V $_{\phi}$ = V $_{SH}$ = V $_{RS}$ = V $_{CP}$ = 5 V (PULSE), f $_{\phi}$ = 1 MHz, LOAD RESISTANCE = 100 k $_{\Omega}$, t $_{INT}$ (INTEGRATION TIME) = 10 ms, LIGHT SOURCE = A LIGHT SOURCE + CM500S FILTER (t = 1.0 mm))

CHARACTERISTIC		SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTE
	Red	R _R	5.0	7.2	9.4		
Sensitivity	Green	R_{G}	6.3	9.1	11.9	V / Ix·s	(Note 2)
	Blue	R _B	2.8	4.0	5.2		
Photo Response Non Uniformity		PRNU (1)	_	10	20	%	(Note 3)
		PRNU (3)	_	3	12	mV	(Note 4)
Saturation Output Voltage		V _{SAT}	1.0	1.5	_	V	(Note 5)
Saturation Exposure		SE	0.07	0.14	_	lx∙s	(Note 6)
Dark Signal Voltage		V _{DRK}	_	2.5	5	mV	(Note 7)
Dark Signal Non Uniformity		DSNU	T —	8	12	mV	(Note 8)
DC Power Dissipation		PD	_	800	1200	mW	
Total Transfer Efficiency		TTE	92	_	_	%	
Output Impedance		Z _o	T —	0.2	0.5	kΩ	
DC Signal Output Voltage		Vos	3.0	6.0	8.0	V	(Note 9)
Random Noise		N_{D^σ}	 	1.0	_	mV	(Note 10)

- (Note 2): Sensitivity is defined for each color of signal outputs average when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature.
- (Note 3): PRNU (1) is defined for each color on a single chip by the expressions below when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature.

PRNU (1) =
$$\frac{\Delta \chi}{\overline{\chi}}$$
 × 100 (%)

Where $\overline{\chi}$ is average of total signal outputs and $\Delta\chi$ is the maximum deviation from $\overline{\chi}$

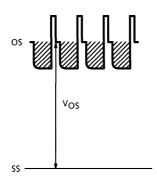
- (Note 4): PRNU (3) is defined as maximum voltage with next pixel, where measured 5% of SE (Typ.).
- (Note 5): V_{SAT} is defined as minimum Saturation Output voltage of all effective pixels.

(Note 6) : Definition of SE : SE =
$$\frac{V_{SAT}}{R_{G}}$$

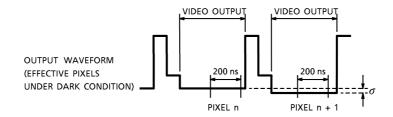
- (Note 7): VDRK is defined as average dark signal voltage of all effective pixels.
- (Note 8) : DSNU is defined as different voltage between V_{DRK} and V_{MDK} , when V_{MDK} is maximum dark voltage.



(Note 9): DC Signal Output Voltage is defined as follows:



(Note 10): Random noise is defined as the standard deviation (sigma) of the output level difference between two adjacent effective pixels under no illumination (i.e. dark condition) calculated by the following procedure.



- 1) Two adjacent pixels (pixel n and n + 1) in one reading are fixed as measurement points.
- 2) Each of the output levels at video output periods averaged over 200 nanosecond period to get Vn and Vn + 1.
- 3) Vn + 1 is subtracted from Vn to get ΔV .

$$\Delta V = Vn - Vn + 1$$

4) The standard deviation of ΔV is calculated after procedure 2) and 3) are repeated 30 times (30 readings).

$$\overline{\Delta V} = \frac{1}{30} \sum_{i=1}^{30} |\Delta Vi| \qquad \sigma = \sqrt{\frac{1}{30} \sum_{i=1}^{30} (|\Delta Vi| - \overline{\Delta V})^2}$$

5) Procedure 2), 3) and 4) are repeated 10 times to get 10 sigma values.

$$\overline{\sigma} = \frac{1}{10} \sum_{j=1}^{10} \sigma^{j}$$

6) $\overline{\sigma}$ value calculated using the above procedure is observed $\sqrt{2}$ times larger than that measured relative to the ground level. So we specify the random noise as follows.

Random noise =
$$\frac{1}{\sqrt{2}} \overline{\sigma}$$

OPERATING CONDITION

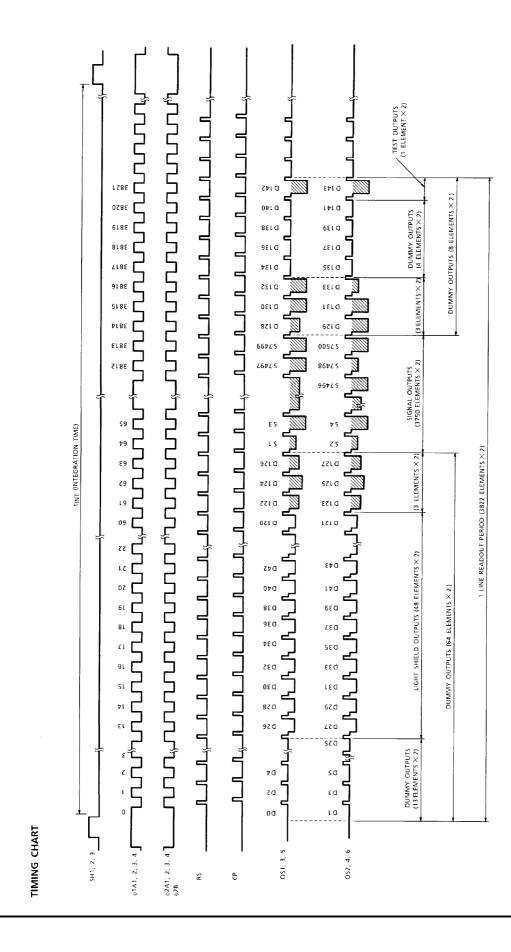
CHARACTERIST	IC	SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTE
Clark Duka Valtana	"H"Level	VφA	4.5	5.0	5.5	V	
Clock Pulse Voltage	"L" Level		0	_	0.5		
Final Stage Clock Pulse	"H"Level	VφB	4.5	5.0	5.5	V	
Voltage	"L" Level		0	_	0.5		
Shift Pulse Voltage	"H"Level	V _{SH}	VøA"H"-0.5	Vφ Α" H"	V <i></i> ∕ A"H"	V	(Note 11)
	"L" Level		0	_	0.5		
Poset Bulse Valters	"H"Level	V	4.5	5.0	5.5	V	
Reset Pulse Voltage	"L" Level	V _{RS}	0	_	0.5		
Clamp Pulse Voltage	"H"Level	\/	4.5	5.0	5.5	V	
	"L" Level	V _{CP}	0	_	0.5	\ \ \	
Power Supply Voltage		V _{OD}	11.4	12.0	13.0	V	

(Note 11) : $V\phi A''H''$ means the high level voltage of $V\phi A$ when SH pulse is high level.

CLOCK CHARACTERISTICS (Ta = 25°C)

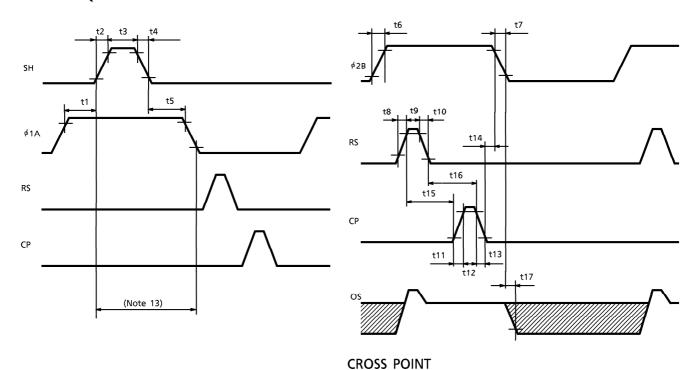
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTE
Clock Pulse Frequency	fφ	_	1	20	MHz	
Reset Pulse Frequency	f _{RS}	_	1	20	MHz	
Clamp Pulse Frequency	fCP	_	1	20	MHz	
Clock Capacitance (Note 12)	C∮A	_	150	_	pF	
Final Stage Clock Capacitance	C∮B	_	20	_	pF	
Reset Gate Capacitance	C _{RS}	_	20	_	pF	
Shift Gate Capacitance	C _{SH}	_	40	_	pF	
Clamp Gate Capacitance	C _{CP}	_	20	_	pF	

(Note 12) : $V_{OD} = 12 V$



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TIMING REQUIREMENTS



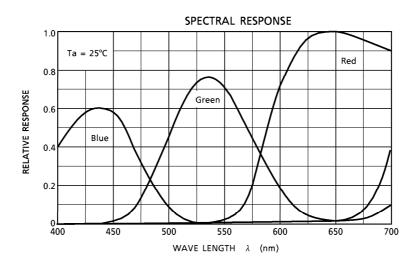
GND 1.5 V (MIN.) 1.5 V (MIN.)

(Note 13): Each RS and CP pins put to Low level during this period.

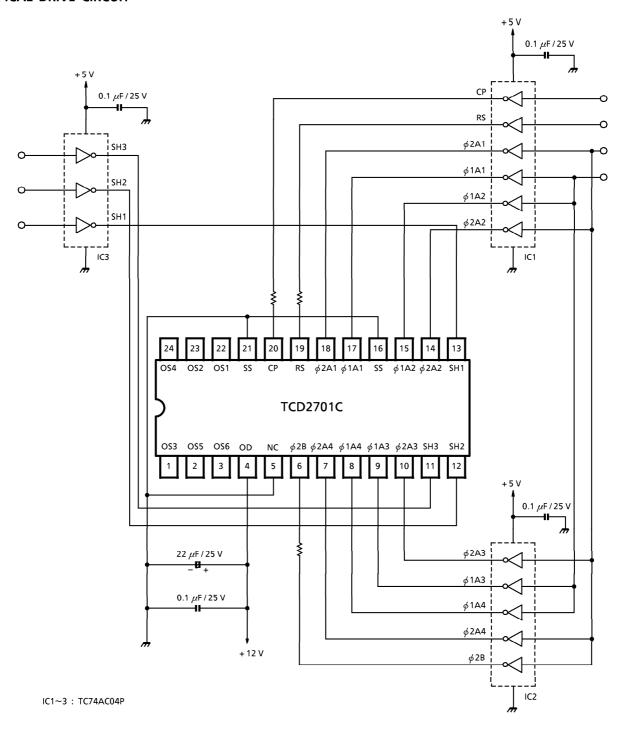
CHARACTERISTIC	SYMBOL	MIN.	TYP. (Note 14)	MAX.	UNIT	
Bulsa Timing of SH and /1A	t1	60	1000	_	nc	
Pulse Timing of SH and ϕ 1A	t5	500	1000	_	ns	
SH Pulse Rise Time, Fall Time	t2, t4	0	50	_	ns	
SH Pulse Width	t3	1000	2000	_	ns	
ϕ 1, ϕ 2 Pulse Rise Time, Fall Time	t6, t7	0	50	_	ns	
RS Pulse Rise Time, Fall Time	t8, t10	0	20	_	ns	
RS Pulse Width	t9	10	100	_	ns	
CP Pulse Rise Time, Fall Time	t11, t13	0	20	_	ns	
CP Pulse Width	t12	10	100	_	ns	
Pulse Timing of ϕ 2B and CP	t14	5	40	_	ns	
Dulco Timing of DC and CD	t15	0	100	_	20	
Pulse Timing of RS and CP	t16	10	100	_	ns	
Video Data Delay Time (Note	15) t17	_	15	_	ns	

(Note 14) : TYP. is the case of fRS = 1 MHz. (Note 15) : Load Resistance is 100 k $\Omega.$

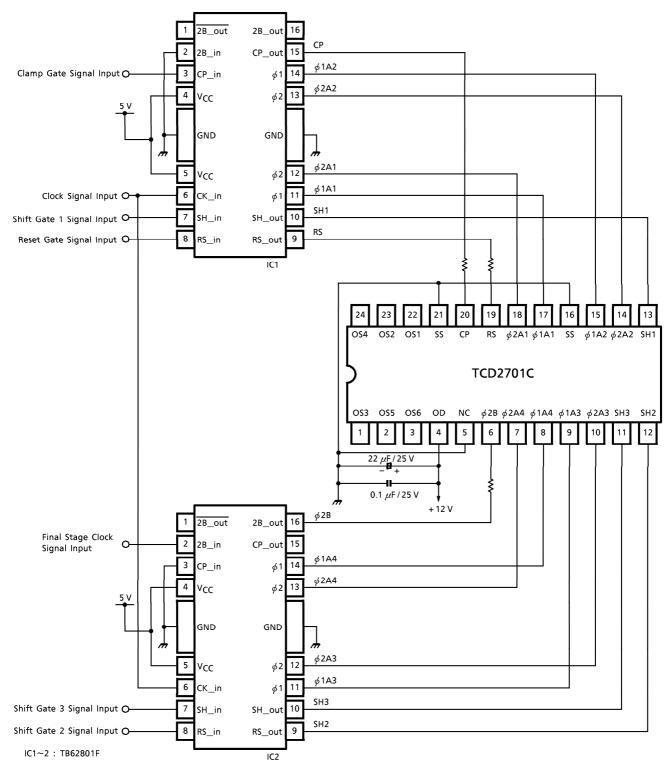
TYPICAL SPECTRAL RESPONSE



TYPICAL DRIVE CIRCUIT



TYPICAL DRIVE CIRCUIT



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PRECAUTIONS FOR USE OF CCD IMAGE SENSOR

1. Static Electricity

CCD Image Sensor is protected against static electricity, but inferior puncture mode device due to static electricity is sometimes detected. In handling the device, it is necessary to execute the following static electricity preventive measures, in order to prevent the trouble rate increase of the manufacturing system due to static electricity.

- a. Prevent the generation of static electricity due to friction by making the work with bare hands or by putting on cotton gloves and non-charging working clothes.
- b. Discharge the static electricity by providing earth plate or earth wire on the floor, door or stand of the work room.
- c. Ground the tools such as soldering iron, radio cutting plier or pincette.
 It is not necessarily required to execute all precaution items for static electricity.
 It is all right to mitigate the precautions by confirming that the trouble rate within the prescribed range.

2 Window Glass

As the dust and station on the glass window of the package will cause black flow on the picture, never fail to clean the glass surface before using. (Blow compressed vapor, and wipe off the dust, and dirt with soft cloth or paper slightly moistened with alcohol). Fully take care for the handling of the device as the window glass will break or a strong friction is given to the window glass surface.

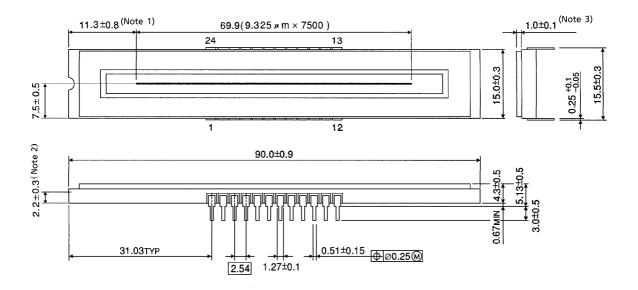
3. Incident Light

CCD image sensor has sensitivity in a wide range zone of light wave length, but its characteristics will sometimes widely change when used with long wave length input light outside the visual light zone.

PACKAGE DIMENSIONS

WDIP24-C-600-2.54 (E)

Unit in mm



- (Note 1) No. 1 SENSOR ELEMENT (S1) TO EDGE OF PACKAGE.
- (Note 2) TOP OF CHIP TO BOTTOM OF PACKAGE.
- (Note 3) GLASS THICKNES (n = 1.5)

Weight: 17.1 g (Typ.)